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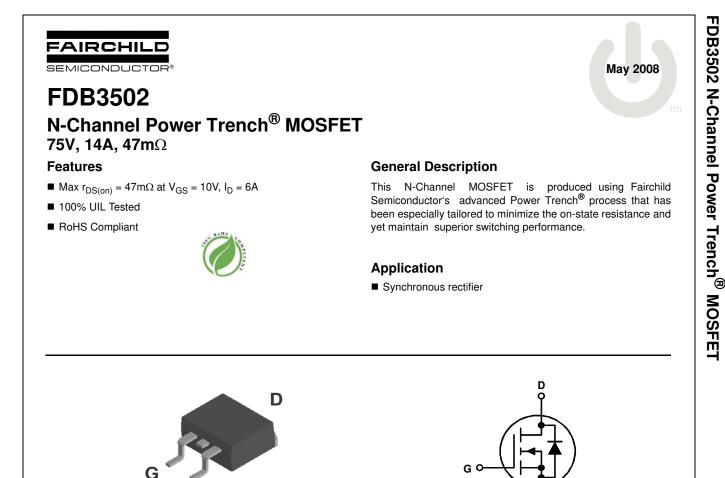


## **ON Semiconductor**®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="https://www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="https://www.onsemi.com">Fairchild\_questions@onsemi.com</a>.

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### MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

TO-263AB FDB Series

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Symbol	Parameter	Ratings	Units			
V <sub>DS</sub>	Drain to Source Voltage	75	V			
V <sub>GS</sub>	Gate to Source Voltage			±20	V	
	Drain Current -Continuous (Package limited)	T <sub>C</sub> = 25°C		14		
	-Continuous (Silicon limited)	T <sub>C</sub> = 25°C		22	^	
ID	-Continuous	$T_A = 25^{\circ}C$	(Note 1a)	6	Α	
	-Pulsed			40		
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	54	mJ	
P <sub>D</sub>	Power Dissipation	T <sub>C</sub> = 25°C		41	w	
	Power Dissipation	(Note 1a)	3.1	VV		
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C	

#### Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	3	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1	a) 40	0/00

#### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB3502	FDB3502	TO-263AB	330 mm	24 mm	800 units

FDB3502
N-Channel
Power 1
Trench <sup>®</sup>
MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	75			V	
ΔΒV <sub>DSS</sub> ΔΤ <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$ , referenced to 25°C		70		mV/°C	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 60V,$			1	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA	
On Chara	octeristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2.5	3.8	4.5	V	
$\Delta V_{GS(th)} \Delta T_J$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$ , referenced to 25°C		-10		mV/°C	
u	Static Drain to Source On Resistance	$V_{GS} = 10V, I_D = 6A$		37	47		
DS(on)		$V_{GS} = 10V, I_D = 6A, T_J = 125^{\circ}C$		63	80	mΩ	
9 <sub>FS</sub>	Forward Transconductance	$V_{DD} = 10V, I_D = 6A$		13		S	
Dynamic	Characteristics						
C <sub>iss</sub>	Input Capacitance			615	815	pF	
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V, f = 1MHz		75	105	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance			35	40	pF	
R <sub>g</sub>	Gate Resistance	f = 1MHz		1.5		Ω	
Switching	characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time			9	17	ns	
t <sub>r</sub>	Rise Time	$V_{DD} = 40V, I_D = 6A,$		3	10	ns	
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10V, R_{GEN} = 6\Omega$		13	22	ns	
f	Fall Time			3	10	ns	
ე <sub>g</sub>	Total Gate Charge at 10V	V 40V		11	15	nC	
Q <sub>gs</sub>	Gate to Source Charge	— V <sub>DD</sub> = 40V — I <sub>D</sub> = 6A		4		nC	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			3		nC	

V	Source to Drain Diode Forward Voltage	$V_{GS} = 0V, I_{S} = 2.6A$	(Note 2)	0.78	1.2	V
V <sub>SD</sub>	Source to Drain Diode Torward Voltage	$V_{GS} = 0V, I_S = 6A$	(Note 2)	0.83	1.3	v
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 6A, di/dt = 100A/µs		25	41	ns
Q <sub>rr</sub>	Reverse Recovery Charge			17	32	nC

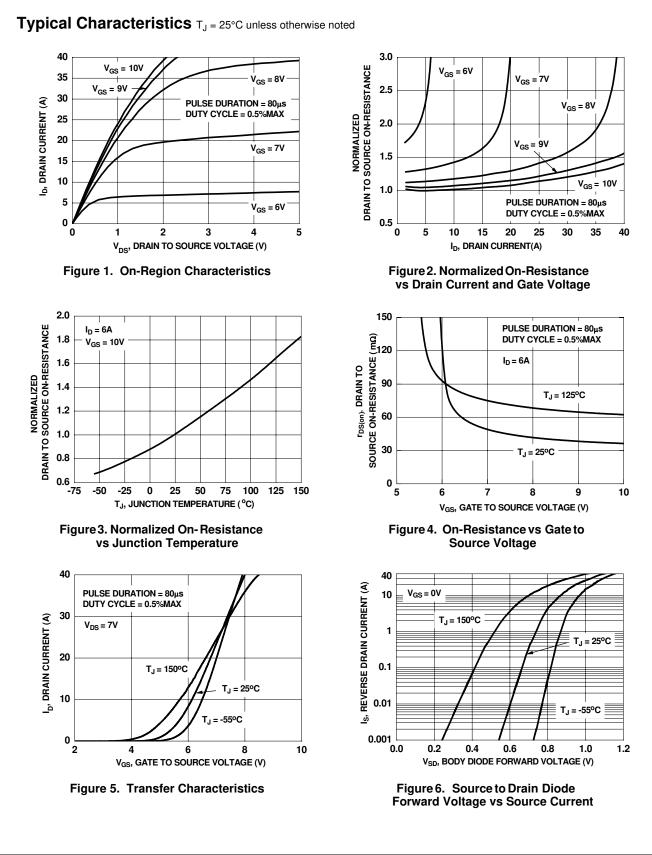
Notes:

1: R<sub>0,J</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0,JC</sub> is guaranteed by design while R<sub>0,JA</sub> is determined by the user's board design.

a. 40°C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper b. 62.5°C/W when mounted on a minimum pad.

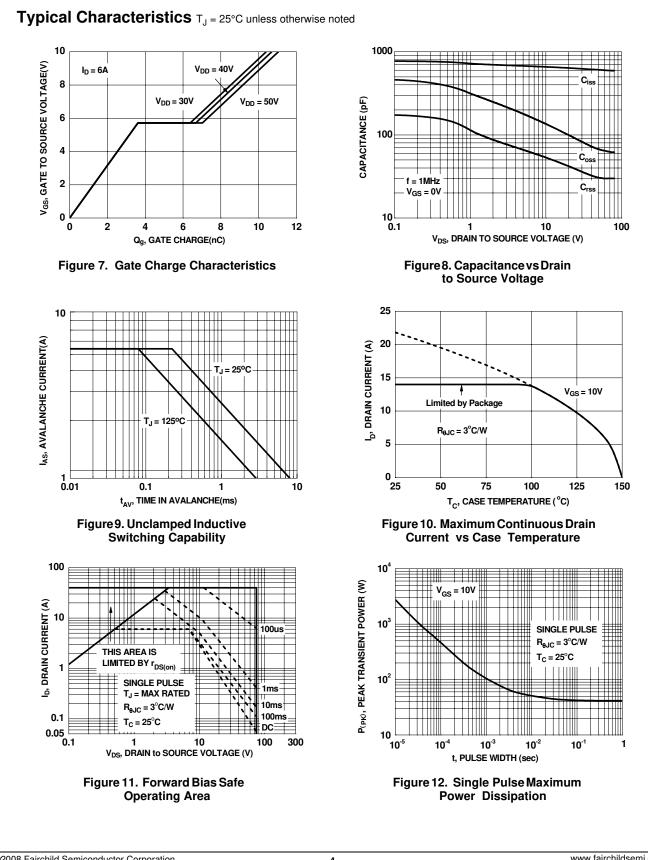
2: Pulse Test: Pulse Width < 300 $\mu$ s, Duty cycle < 2.0%.

3: Starting  $T_J$  = 25°C, L = 3mH,  $I_{AS}$  = 6A,  $V_{DD}$  = 75V,  $V_{GS}$  = 10V.



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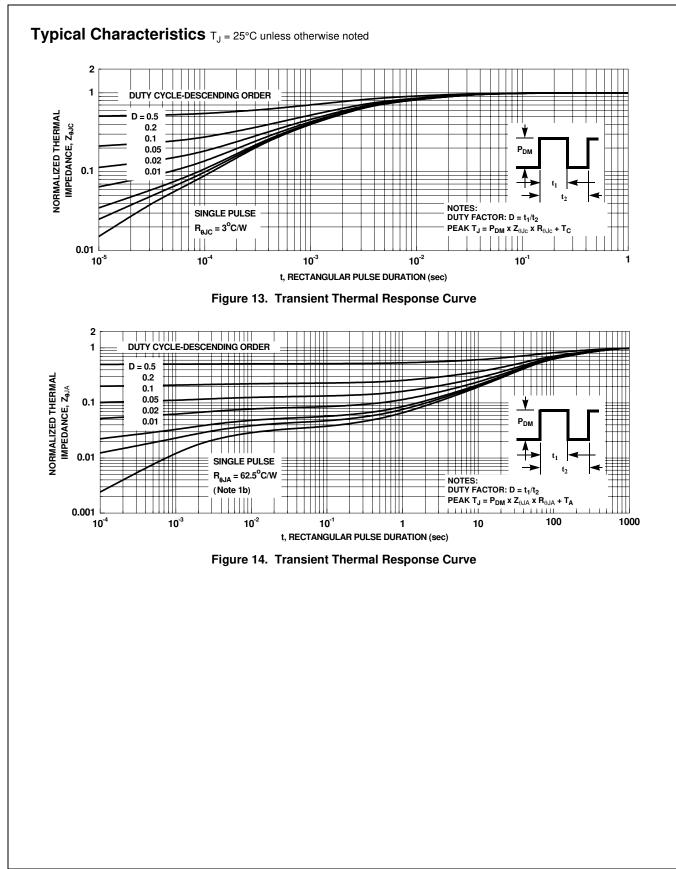
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